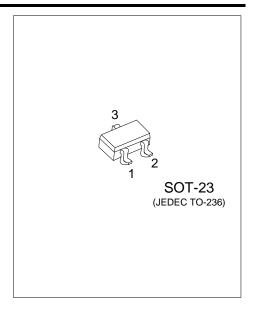
# **MMBT9015**

# PNP SILICON TRANSISTOR

# PRE-AMPLIFIER, LOW LEVEL & LOW NOISE

#### ■ FEATURES

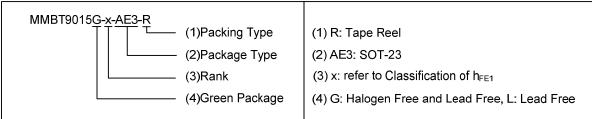
- \*High total power dissipation. (450mW)
- \*Excellent hFE linearity.
- \*Complementary to UTC MMBT9014



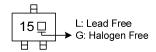
#### **■ ORDERING INFORMATION**

Ordering	Number	Dookogo	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MMBT9015L-x-AE3-R	MMBT9015G-x-AE3-R	SOT-23	В	Е	С	Tape Reel	

Note: Pin Assignment: B: Base E: Emitter C: Collector



#### **■** MARKING



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# ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	$V_{CEO}$	-45	V
Collector-Base Voltage	$V_{CBO}$	-50	V
Emitter Base Voltage	$V_{EBO}$	-5	V
Collector Current	Ic	-100	mA
Collector dissipation	Pc	225	mW
Junction Temperature	$T_J$	+150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ <b>+</b> 150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Voltage	$V_{CEO}$	I <sub>C</sub> =-100μA, I <sub>E</sub> =0	-50			V
Collector-Base Voltage	$V_{CBO}$	$I_C=-1$ mA, $I_B=0$	-45			V
Emitter Base Voltage	$V_{EBO}$	I <sub>E</sub> =-100μA, I <sub>C</sub> =0	-5			V
Collector cutoff current	I <sub>CBO</sub>	$V_{CB}$ =-50V, $I_E$ =0			-50	nA
Emitter Cutoff Current	I <sub>EBO</sub>	$V_{EB}$ =-5V, $I_C$ =0			-100	nA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =-5V,Ic=-1mA	60	200	600	
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C$ =-100mA, $I_B$ =-5mA		-0.2	-0.7	V
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	$I_C$ =-100mA, $I_B$ =-5mA		-0.82	-1.0	V
Base-emitter on voltage	$V_{BE(ON)}$	$V_{CE}$ =-5V, $I_{C}$ =-2mA	-0.6	-0.65	-0.75	V
Current-Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10mA	100	190		MHz
Output Capacitance	C <sub>OB</sub>	V <sub>CB</sub> =-10V, I <sub>E</sub> =0, f=1MHz		4.5	7.0	pF
Noise Figure	NF	$V_{CE}$ =-5 $V$ , $I_{C}$ =-0.2 $m$ A, $f$ =1 $K$ Hz, $R_{S}$ =-1 $K$ $\Omega$		0.7	10	dB

# CLASSIFICATION OF $h_{\rm FE}$

RANK	А	В	С	
RANGE	60-150	100-300	200-600	



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